

G PTR1334

PHASE CONTROLLED SCR

High reliability operation

DC power supply

Controlled rectifiers

BLOCKING VOLTAGE UP TO 800 V

AVERAGE CURRENT 3345 A

SURGE CURRENT 43 kA

BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
V _{RRM}	Repetitive peak reverse voltage	800 V
V _{RSM}	Non-repetitive peak reverse voltage	900 V
V _{DRM}	Repetitive peak off-state voltage	800 V
I _{IDRM}	Repetitive peak off-state current, max.	V _{DRM} , single phase, half wave, T _j = T _{jmax} 150 mA
I _{IRRM}	Repetitive peak reverse current, max.	V _{RRM} , single phase, half wave, T _j = T _{jmax} 150 mA

ON-STATE CHARACTERISTICS

I _{T(AV)}	Average on-state current	Sine wave, 180° conduction, Th = 55 °C	3345 A
I _{T(RMS)}	R.M.S. on-state current	Sine wave, 180° conduction, Th = 55 °C	5254 A
I _{TSM}	Surge on-state current	Non rep. half sine wave, 50 Hz, V _R = 0 V, T _j = T _{jmax}	43 kA
I ² t	I ² t for fusing coordination		9245 kA ² s
V _{T(TO)}	Threshold voltage	T _j = T _{jmax}	0.9 V
I _T	On-state slope resistance	T _j = T _{jmax}	0.12 mΩ
V _{TM}	Peak on-state voltage, max	On-state current I _T = 6000 A, T _j = T _{jmax}	1.6 V
I _H	Holding current, max	T _j = 25 °C	300 mA
I _L	Latching current, typ	T _j = 25 °C	1500 mA

TRIGGERING CHARACTERISTICS

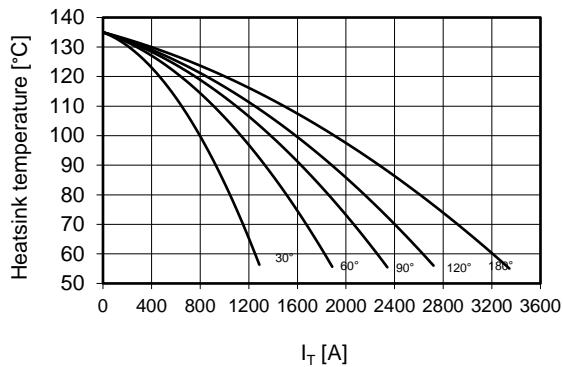
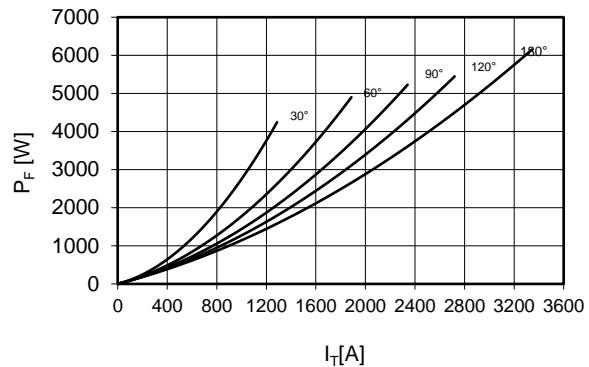
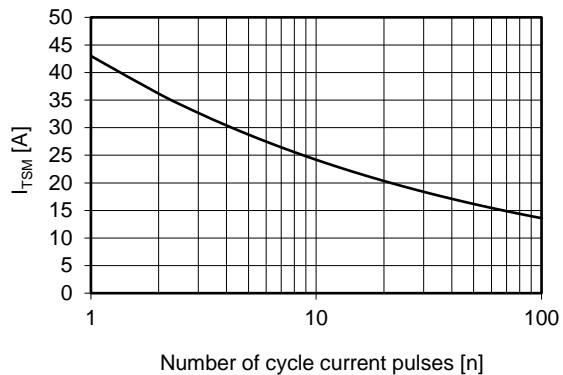
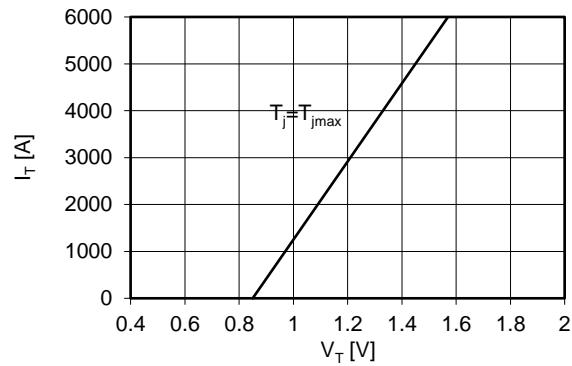
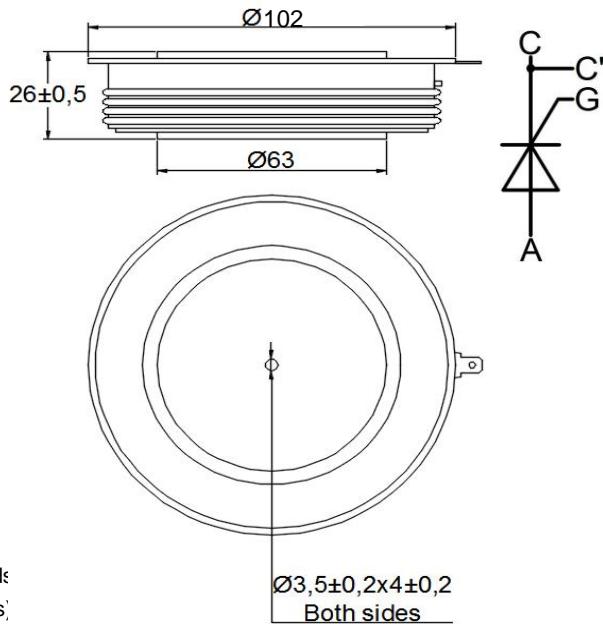
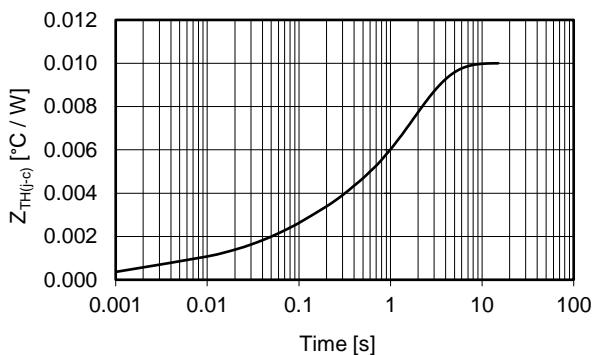
V _{GT}	Gate trigger voltage	T _j = 25 °C, V _D = 12 V	3 V
I _{GT}	Gate trigger current	T _j = 25 °C, V _D = 12 V	300 mA
V _{GD}	Non-trigger voltage	V _D = 67% V _{RRM} , T _j = T _{jmax}	0.35 V
P _{GM}	Peak gate power dissipation	Pulse width 0.5 ms	150 W
P _{G(AV)}	Average gate power dissipation		5 W
I _{FGM}	Peak gate current		8 A
V _{FGM}	Peak gate voltage (forward)		25 V
V _{RG M}	Peak gate voltage (reverse)		5 V

SWITCHING CHARACTERISTICS

di/dt	Critical rate of rise of on-state current	T _j = T _{jmax} , I _G = 2 A, dI/dt ≥ 1 A/μs	200 A/μs
dV/dt	Critical rate of rise of off-state voltage	T _j = T _{jmax}	1000 V/μs
t _q	Turn-off time, typ	T _j = T _{jmax} , I _T = 2000 A, di/dt = -10 A/μs VR = 100 V, VD = 67% V _{DRM} , dV/dt = 50 V/μs	350 μs

THERMAL AND MECHANICAL CHARACTERISTICS

R _{th(j-c)}	Thermal resistance (junction to case)	Double side cooled	0.010 °C/W
R _{th(c-h)}	Thermal resistance (case to heatsink)	Double side cooled	0.003 °C/W
T _{jmax}	Max operating junction temperature		135 °C
T _{stg}	Storage temperature		-40 / 135 °C
F	Clamping force ± 10%		40 kN
	Mass		1000 g

Current rating - sine wave

Power loss - sine wave

**Maximum surge current
d.s. cooled**

On-state voltage drop

Thermal impedance (j-c)


Ordering information GPTR1334-VVGL

VV: blocking voltage / 100 (e.g. 08 for 800 V)

G: trigger lead type (**S** = straight **T** = twisted **blank** = no leads)

L: trigger lead length x 100mm (3 - 4 - 5 - 7 **blank** = no leads,

In the interest of product improvement Green Power Solutions reserves the right to change any specification given in this data sheet without notice.